

Changchun New Industries Optoelectronics Tech, Co., Ltd,

DATA SHEET

PRL-FS-637/1~200mW

SPECIFICATIONS

RED DIODE LASER AT 637 nm

Red diode laser at 637 nm is made features of round beam, ultra compact, long lifetime, low cost and easy operating, which is widely used in collimation, laser medical treatment, scientific experiment, optical instrument, laser display, laser lighting show, etc.



Wavelength (nm)	637±5	
Operating mode	CW	
Output power (mW)	>1, 10, 30,, 200	
Power stability (rms, over 4 hours)	<1%, <3%, <5%	
Transverse mode	Near TEM ₀₀	
Beam diameter at the aperture (1/e ² , mm)	~3.5	
Beam divergence, full angle (mrad)	<1.0	
Warm-up time (minutes)	<10	
Beam height from base plate (mm)	15	
Operating temperature (°C)	10~35	AVOID EXPOSURE: Laser radiation is emitted from t
Power supply (90-264VAC)	PSU-V-OEM	
TTL/Analog modulation	TTL on/off, 1Hz-1KHz, 1KHz-10KHz, 10KHz-30KHz; and Analog modulation option	LASER RADIATION - KNOD DIRECT EXPOSURE TO BEAM
Expected lifetime (hours)	10000	CLASS IIIb LASER PRODUCT This device complies with 21 CFR1040.10 and 1040.11
Warranty period	1 year	Changchun New Industries Optoelectronics Tech. Co., Ltd. (CNI 888 JinHu Road High-tech Zone Changchun, China

